EM513 THRU EM518

1.0 AMP SILICON RECTIFIERS



VOLTAGE RANGE
1600 to 2000 Volts
CURRENT
1.0 Ampere

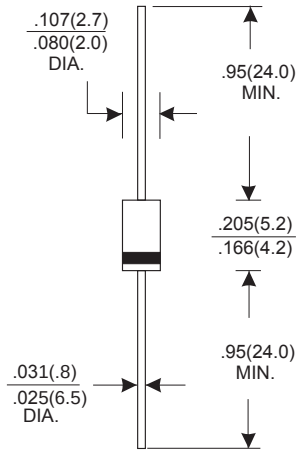
FEATURES

* Low forward voltage drop
* High current capability
* High reliability
* High surge current capability

MECHANICAL DATA

* Case: Molded plastic
* Epoxy: UL 94V-0 rate flame retardant
* Lead: Axial leads, solderable per MIL-STD-202, method 208 guranteed
* Polarity: Color band denotes cathode end
* Mounting position: Any
* Weight: 0.28 grams
* Lead Free Finish/RoHS Compliant

DO-41



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25℃ ambient temperature uniess otherwies specified.
Single phase half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

TYPE NUMBER	EM513	EM516	EM518	UNITS
Maximum Recurrent Peak Reverse Voltage	1600	1800	2000	V
Maximum RMS Voltage	1120	1260	1400	V
Maximum DC Blocking Voltage	1600	1800	2000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=75℃	1.0			A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	30			A
Maximum Instantaneous Forward Voltage at 1.0A	1.1			V
Maximum DC Reverse Current Ta=25℃	5.0			μA
at Rated DC Blocking Voltage Ta=100℃	50			μA
Typical Junction Capacitance (Note 1)	15			pF
Typical Thermal Resistance RθJA (Note 2)	50			℃/W
Operating and Storage Temperature Range T_J, T_{STG}	-65 — +150			℃

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance from Junction to Ambient .375" (9.5mm) lead length.

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RATING AND CHARACTERISTIC CURVES (EM513~EM518)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

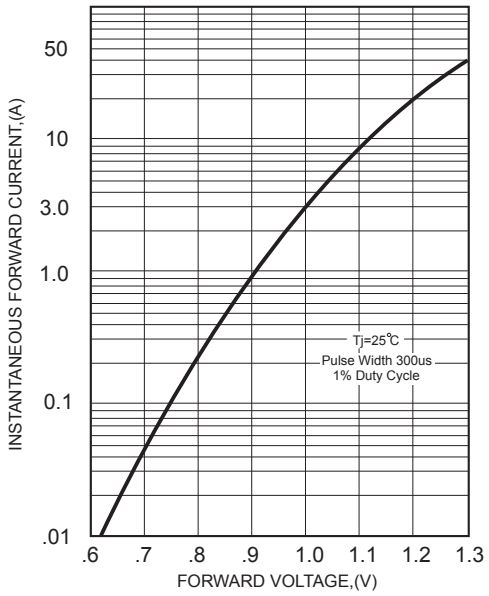


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

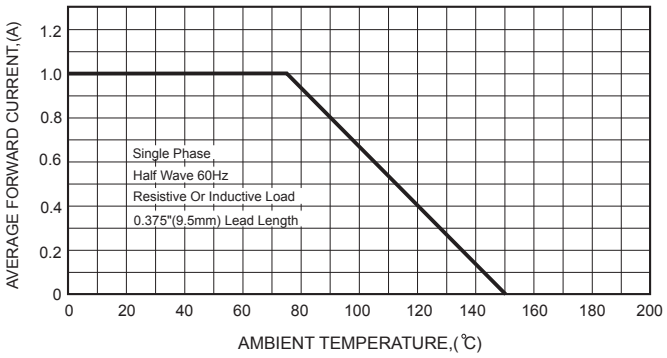


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

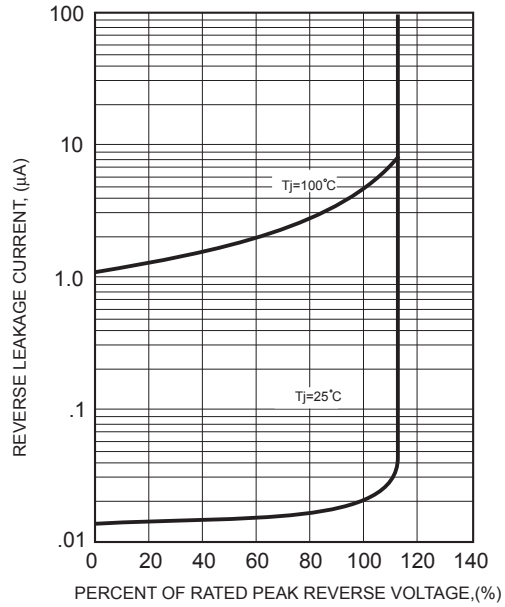


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

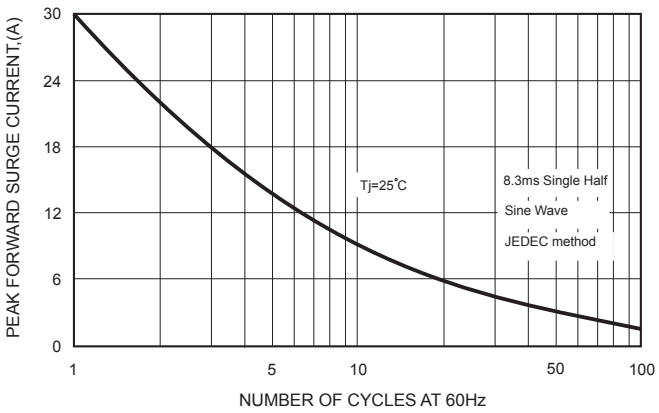
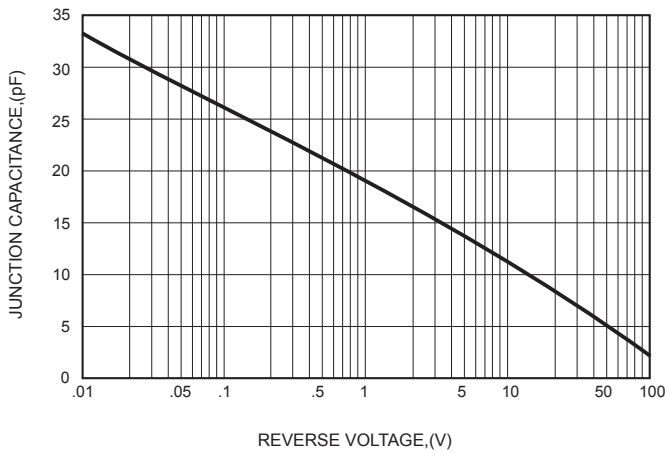


FIG.5-TYPICAL JUNCTION CAPACITANCE



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